

C3D04060E Silicon Carbide Schottky Diode *Z-REC®* RECTIFIER

Features

- 600-Volt Schottky Rectifier
- Optimized for PFC Boost Diode Application
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- Switch Mode Power Supplies (SMPS)
- Boost diodes in PFC or DC/DC stages
- Free Wheeling Diodes in Inverter stages
- AC/DC converters

Maximum Ratings ($T_c = 25$ °C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
V _{RRM}	Repetitive Peak Reverse Voltage	600	v		
V _{RSM}	Surge Peak Reverse Voltage	600	V		
V _{DC}	DC Blocking Voltage	600	V		
I _F	Continuous Forward Current	13.5 6 4	А	T _c =25°C T _c =135°C T _c =155°C	Fig. 3
I _{FRM}	Repetitive Peak Forward Surge Current	17 12	А	$T_c=25$ °C, $t_p=10$ ms, Half Sine Wave $T_c=110$ °C, $t_p=10$ ms, Half Sine Wave	
I _{fsm}	Non-Repetitive Peak Forward Surge Current	25 19	A	$T_c = 25$ °C, $t_p = 10$ ms, Half Sine Wave $T_c = 110$ °C, $t_p = 10$ ms, Half Sine Wave	Fig. 8
$\mathbf{I}_{\mathrm{F,Max}}$	Non-Repetitive Peak Forward Surge Current	220 160	А	$T_c=25$ °C, $t_p=10 \ \mu$ s, Pulse $T_c=110$ °C, $t_p=10 \ \mu$ s, Pulse	Fig. 8
P _{tot}	Power Dissipation	52 22.5	W	$T_c = 25^{\circ}C$ $T_c = 110^{\circ}C$	Fig. 4
dV/dt	Diode dV/dt ruggedness	200	V/ns	V _R =0-600V	
∫i²dt	i²t value	3.1 1.8	A ² s	$T_c=25$ °C, t _p =10 ms $T_c=110$ °C, t _p =10 ms	
T _J , T _{stg}	Operating Junction and Storage Temperature	-55 to +175	°C		

Package



V_{RRM}

Q

I_c (T_c=135°C)

600 V

10 nC

6 A

=

=

=

TO-252-2





Part Number	Package	Marking	
C3D04060E	TO-252-2	C3D04060	

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Electrical Characteristics

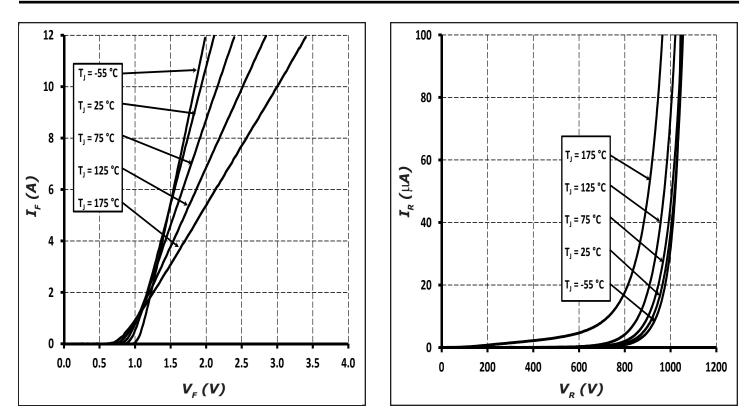
Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V _F	Forward Voltage	1.4 1.7	1.7 2.4	V	$I_F = 4 A T_J = 25 °C$ $I_F = 4 A T_J = 175 °C$	Fig. 1
I _R	Reverse Current	5 10	25 100	μA	V _R = 600 V T _j =25°C V _R = 600 V T _j =175°C	Fig. 2
Q _c	Total Capacitive Charge	10		nC	$V_{R} = 400 V, I_{F} = 4 A$ $di/dt = 500 A/\mu s$ $T_{J} = 25^{\circ}C$	Fig. 5
С	Total Capacitance	231 18.5 15		pF	$V_{R} = 0 V, T_{J} = 25^{\circ}C, f = 1 MHz$ $V_{R} = 200 V, T_{J} = 25^{\circ}C, f = 1 MHz$ $V_{R} = 400 V, T_{J} = 25^{\circ}C, f = 1 MHz$	
E _c	Capacitance Stored Energy	1.4		μJ	V _R = 400 V	Fig. 7

Note: This is a majority carrier diode, so there is no reverse recovery charge.

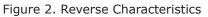
Thermal Characteristics

Symbol	Parameter	Тур.	Unit	Note
$R_{_{ extsf{ heta}JC}}$	Thermal Resistance from Junction to Case	2.9	°C/W	Fig. 9

Typical Performance









Typical Performance

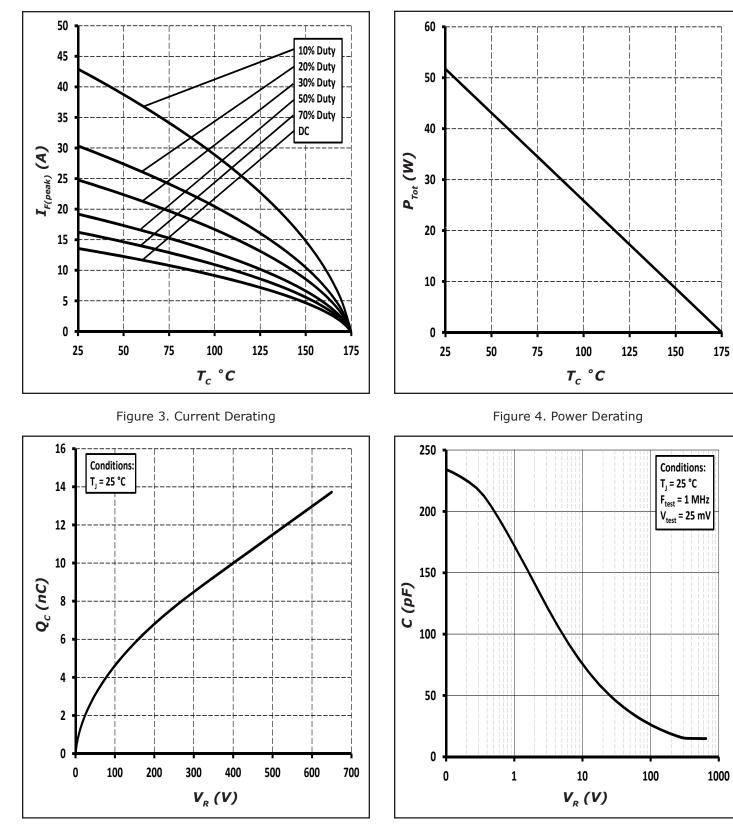
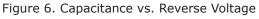


Figure 5. Total Capacitance Charge vs. Reverse Voltage



3



Typical Performance

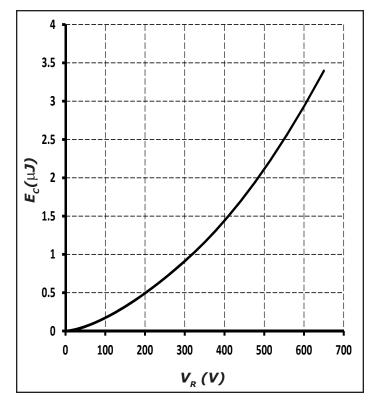


Figure 7. Capacitance Stored Energy

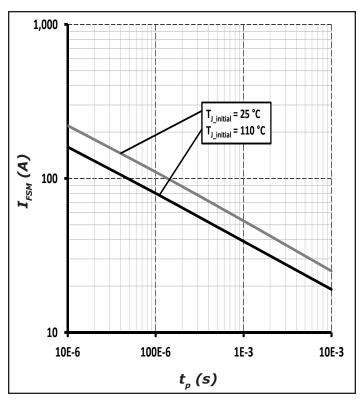


Figure 8. Non-repetitive peak forward surge current versus pulse duration (sinusoidal waveform)

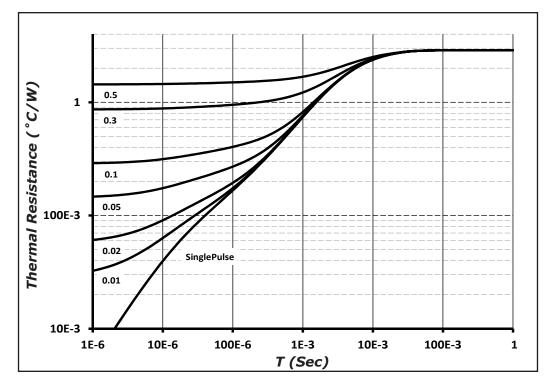
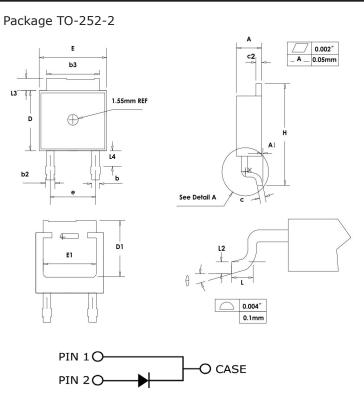


Figure 9. Transient Thermal Impedance

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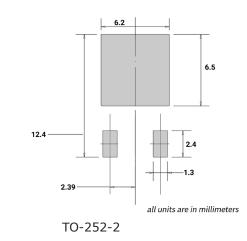


Package Dimensions



CVMDOI	MILLIMETERS			
SYMBOL	MIN	MAX		
А	2.159	2.413		
A1	0	0.13		
b	0.64	0.89		
b2	0.653	1.143		
b3	5.004	5.6		
С	0.457	0.61		
c2	0.457	0.864		
D	5.867	6.248		
D1	5.21	-		
E	6.35	7.341		
E1	4.32	-		
е	4.58	BSC		
Н	9.65	10.414		
L	1.106	1.78		
L2	0.51 BSC			
L3	0.889	1.27		
L4	0.64 1.01			
θ	0°	8°		

Recommended Solder Pad Layout



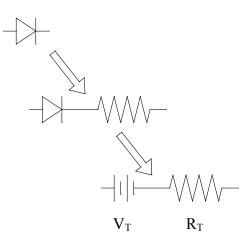
Part Number	Package	Marking	
C3D04060E	TO-252-2	C3D04060	



Note: Recommended soldering profiles can be found in the applications note here: http://www.wolfspeed.com/power_app_notes/soldering



Diode Model



	Vf _⊤ =	$V_T +$	If * I	R _T	
V _T =	= 1.00) + (T	;*-:	1.1*:	10-3)
	= 0.06				

Note: T_j = Diode Junction Temperature In Degrees Celsius, valid from 25°C to 175°C

Notes

• RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented January 2, 2013. RoHS Declarations for this product can be obtained from your Wolfpseed representative or from the Product Ecology section of our website at http://www.wolfspeed.com/Power/Tools-and-Support/Product-Ecology.

• **REACh Compliance**

REACh substances of high concern (SVHCs) information is available for this product. Since the European Chemical Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact a Cree representative to insure you get the most up-to-date REACh SVHC Declaration. REACh banned substance information (REACh Article 67) is also available upon request.

This product has not been designed or tested for use in, and is not intended for use in, applications implanted into
the human body nor in applications in which failure of the product could lead to death, personal injury or property
damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines,
cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control
systems, or air traffic control systems.

Related Links

- Cree SiC Schottky diode portfolio: http://www.wolfspeed.com/Power/Products#SiCSchottkyDiodes
- Schottky diode Spice models: http://www.wolfspeed.com/power/tools-and-support/DIODE-model-request2
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- SiC MOSFET and diode reference designs: http://go.pardot.com/l/101562/2015-07-31/349i

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